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## Synthesis of silver sulfide nanoparticles and their photodetector applications†

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Silver sulfide nanoparticles (Ag<sub>2</sub>S NPs) are currently being explored as infrared active nanomaterials that can provide environmentally stable alternatives to heavy metals such as lead. In this paper, we describe the novel synthesis of Ag<sub>2</sub>S NPs by using a sonochemistry method and the fabrication of photodetector devices through the integration of Ag<sub>2</sub>S NPs atop a graphene sheet. We have also synthesized Li-doped Ag<sub>2</sub>S NPs that exhibited a significantly enhanced photodetector sensitivity *via* their enhanced absorption ability in the UV-NIR region. First-principles calculations based on a density functional theory formalism indicated that Li-doping produced a dramatic enhancement of NIR photoluminescence of the Ag<sub>2</sub>S NPs. Finally, high-performance photodetectors based on CVD graphene and Ag<sub>2</sub>S NPs were demonstrated and investigated; the hybrid photodetectors based on Ag<sub>2</sub>S NPs and Li-doped Ag<sub>2</sub>S NPs exhibited a photoresponse of 2723.2 and 4146.0 A W<sup>-1</sup> respectively under a light exposure of 0.89 mW cm<sup>-2</sup> at 550 nm. Our novel approach represents a promising and effective method for the synthesis of eco-friendly semiconducting NPs for photoelectric devices.

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## Introduction

Ultraviolet (UV), visible, and near infrared (NIR) imaging with nanoparticles (NPs) has been extensively investigated owing to their utility in many applications, such as electroluminescent devices, optical modulators, photodetectors, and biological fluorophores.<sup>1–9</sup> Recently, quantum dot NPs, such as PbS and PbSe, have particularly emerged as some of the most promising new materials for the development of advanced photoelectric devices, because of low-cost manufacturing, solution processability, and their superior photoelectric properties including unique absorption and emission of light in the NIR regions.<sup>10–15</sup> However, lead-containing NPs are highly toxic and responsible for extensive environmental contamination and health problems in various parts of the world.<sup>16,17</sup> In order to overcome these limitations, the Ag<sub>2</sub>S NPs have been extensively studied as attractive NIR-absorbing NPs for photovoltaics, photoconductors, and IR detectors due to their high biocompatibility and unique absorption ability in the UV-NIR regions, which can be used as multispectral photodetectors in UV, visible, and NIR spectrum because of their light absorption in a broad wavelength range.<sup>18–27</sup> However, the development of a facile and easy methods for the preparation of the high-quality and monodisperse Ag<sub>2</sub>S NPs is still required for

routine industrial applications including photoelectric devices and photodetectors.

In this study, we demonstrate the facile preparation of Ag<sub>2</sub>S NPs and one-pot synthesis of Li-doped Ag<sub>2</sub>S NPs *via* ultrasonic irradiation, which resulted in a dramatic enhancement of their absorption and emission capabilities in the NIR region. The effect of Li ion doping on the electronic structure of the Ag<sub>2</sub>S system was also investigated by first-principles calculations, which indicated that the Li-doped Ag<sub>2</sub>S NPs could enhance the photoluminescence of semiconducting nanocrystals. Finally, hybrid photodetectors based on transparent CVD graphene nanosheets and Ag<sub>2</sub>S NPs were successfully fabricated. These photodetectors based on pristine Ag<sub>2</sub>S NPs and Li-doped Ag<sub>2</sub>S NPs showed photoresponses of 2723.2 and 4146.0 A W<sup>-1</sup>, respectively, under a light exposure of 0.89 mW cm<sup>-2</sup> at 550 nm. The proposed synthesis and doping methods constitute a facile and efficient approach for fabricating graphene-NP-based hybrid two-dimensional (2D) photoelectric devices for various applications, including flexible devices and advanced phototransistors.

## Results and discussion

The facile synthesis of 10 nm Ag<sub>2</sub>S NPs was performed by using a sonochemical method, in which the decomposition of raw materials is induced by ultrasound under ambient conditions (Fig. 1a). Silver nitrate (AgNO<sub>3</sub>) in 1-dodecanethiol was sonicated to generate localized hot spots within the acoustic cavitation of collapsing bubbles during ultrasonic irradiation

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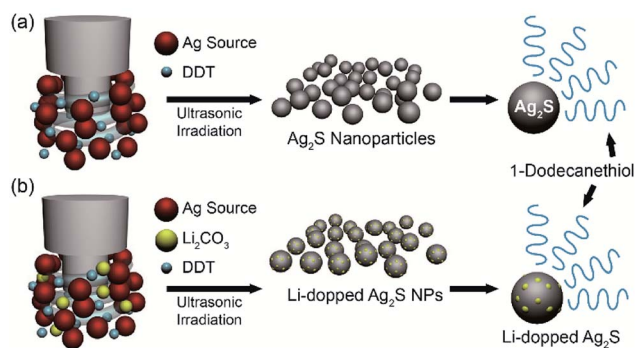


Fig. 1 Synthesis of  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs. Schematic illustration of the synthesis of (a)  $\text{Ag}_2\text{S}$  NPs and (b) Li-doped  $\text{Ag}_2\text{S}$  NPs by using ultrasonic irradiation.

(reaction time: 10 min, power: 50%, temperature:  $\sim 160^\circ\text{C}$ ) (see Fig. S1 in ESI†). In order to improve NIR photodetector sensitivity, Li-doped  $\text{Ag}_2\text{S}$  NPs were also synthesized using a method similar to that used for pristine  $\text{Ag}_2\text{S}$  NPs by adding the appropriate amount of Li in the reaction bottle (Fig. 1b). Such photosensitive materials can lead to an enhancement of the absorption ability in the broad wavelength range, resulting in an overall improvement of their photodetector performance.

Transmission electron microscopy (TEM) analysis was used to characterize the structure and morphology of  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs. The TEM images of the as-prepared  $\text{Ag}_2\text{S}$  NPs confirmed the monodispersity and narrow size distribution of the NPs (Fig. 2a) that can be attributed to the effective separation of the nucleation and growth processes during ultrasonic irradiation at  $160^\circ\text{C}$ . This result was similar to that reported in a previous study.<sup>28</sup>

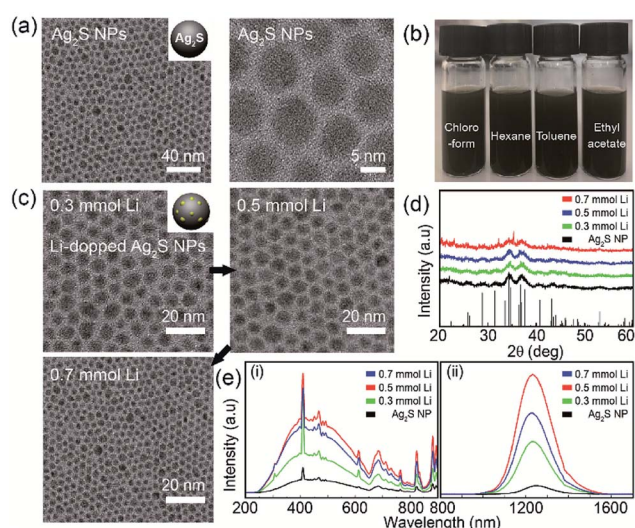


Fig. 2 Synthesis of  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs. (a) Representative TEM images of  $\text{Ag}_2\text{S}$  NPs with a 10 nm size. (b) Optical images of the dispersion of  $\text{Ag}_2\text{S}$  NPs in chloroform, hexane, toluene, and ethyl acetate. (c) XRD patterns of  $\text{Ag}_2\text{S}$  NPs in terms of Li concentrations. (d) TEM images for 0.3 mmol Li-doped (right), 0.5 mmol Li doped (middle), and 0.7 mmol Li-doped (left)  $\text{Ag}_2\text{S}$  NPs. (e) UV-Vis-NIR absorption spectra (left) and PL emission spectra (right) under an excitation of 850 nm (right).

Significantly, the  $\text{Ag}_2\text{S}$  NPs were well dispersed in various organic solvents due to the presence of dodecanethiol coated on the NP surface (Fig. 2b). In the XRD patterns of the  $\text{Ag}_2\text{S}$  NPs doped with different amounts of  $\text{Li}^+$ , most of the peaks corresponded to the monoclinic  $\text{Ag}_2\text{S}$  phase (JCPDS no. 014-0072) (Fig. 2d). The TEM images of Li-doped  $\text{Ag}_2\text{S}$  NPs for different  $\text{Li}^+$  amounts revealed spherical monodisperse NPs; Li contents did not affect particle morphology and size (Fig. 2c). The photoluminescence (PL) excitation and emission spectra of  $\text{Ag}_2\text{S}$  NPs as a function of the Li concentration are shown in Fig. 2e. Unlike general quantum dots, involving PbSe and PbS, these NPs could be effectively excited across the UV-NIR region (See Fig. S2 in ESI†). It has been reported that the  $\text{Ag}_2\text{S}$  NPs emits efficiently under the various excitation ranges, which makes them promising candidates for photodetectors requiring unique absorption in the various wavelength regions (from UV to NIR). As the content of  $\text{Li}^+$  increased, the emission intensities of the  $\text{Ag}_2\text{S}$  NPs increased up to 0.05 mmol and exhibited an emission peak at 1250 nm (Fig. 2e). The Li-doped  $\text{Ag}_2\text{S}$  NPs were found to display a remarkable enhancement of the emission intensity (up to two orders) compared to that of the undoped  $\text{Ag}_2\text{S}$  NPs. It is well known that even at very small concentrations,  $\text{Li}^+$  ions play an important role as co-dopants in increasing the luminescent efficiency of phosphors.<sup>28</sup> In the XPS spectrum, only Ag and S peaks are observed and Li 1S peak is unable to distinguish with Ag 4P at around 55 eV because Li 1S peak and Ag 4P peak overlap each other (see Fig. S3 in ESI†). But ICP analysis confirmed the existence of Li in these  $\text{Ag}_2\text{S}$  NPs (see Fig. S4 in ESI†).

To understand the effect of Li ion doping on the electronic structures of the  $\text{Ag}_2\text{S}$  system, we performed first-principles calculations based on the density functional theory formalism for the Li interstitials and substitutions in crystalline  $\text{Ag}_2\text{S}$ . Fig. 3 (left) shows the optimized atomic geometries of (a)  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$  supercell (321-pristine), (c)  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$  supercell with a Li interstitial (321- $\text{Li}_i$ -1), and (e)  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$  supercell with two Li interstitials (321- $\text{Li}_i$ -2<sub>near</sub>). As shown in Fig. 2d, since the Li contents did not affect the structural properties of  $\text{Ag}_2\text{S}$  NPs, not only interstitial doping but also substitution were considered in our calculations. The Li concentration was about 0.12 wt% for the case of 321- $\text{Li}_i$ -1, which corresponded to the experimental conditions. Although a Li interstitial was added in the interspace of the  $\text{Ag}_2\text{S}$  cell, its crystal structure was well preserved, as shown in Fig. 3c. Furthermore, when an additional Li atom was appended, a local amorphous structure in the doped  $\text{Ag}_2\text{S}$  began to appear (Fig. 3e). Additionally, the calculations for the Li substitutions at the Ag sites in the  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$  supercell were also carried out (See Fig. S5 in ESI†).

Since  $\text{Li}^+$  ions (0.9 Å) have a smaller ionic radius than  $\text{Ag}^+$  ions (1.3 Å) in the  $\text{Ag}_2\text{S}$  crystal, regardless of the number (per unit-cell) of Li substitutions, the crystal structures of doped  $\text{Ag}_2\text{S}$  systems with Li substitutions at the Ag sites were well maintained.<sup>29</sup> Likewise, the electronic structure of  $\text{Ag}_2\text{S}$  hardly changed upon Li substitution (See Fig. S5 in ESI†). However, the Li interstitial in the  $\text{Ag}_2\text{S}$  crystal caused a significant change in the electronic structure. Fig. 3 (right) shows the calculated band structures and projected density of states (PDOS) of (b) 321-



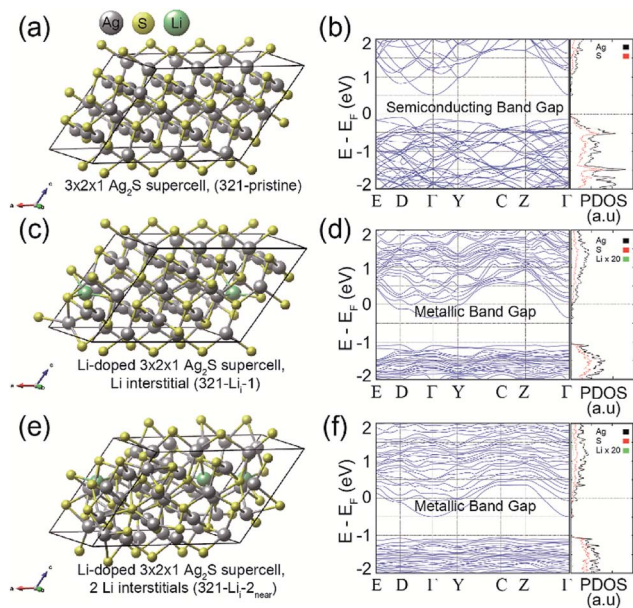


Fig. 3 Calculations for the pristine and Li doped (interstitials)  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$ . Calculated optimized atomic geometries for the (a) 321-pristine, (c) 321- $\text{Li}_i$ -1, and (e) 321- $\text{Li}_i$ -2<sub>near</sub>. The gray, yellow, and green balls represent the Ag, S, and Li atoms, respectively. Calculated band structures and PDOSs for (b) 321-pristine, (d) 321- $\text{Li}_i$ -1, and (f) 321- $\text{Li}_i$ -2<sub>near</sub>. The Fermi levels of all calculated systems were set at zero.

pristine, (d) 321- $\text{Li}_i$ -1, and (f) 321- $\text{Li}_i$ -2<sub>near</sub>. As shown in the band structures of Fig. 3b and d, the bottom of the conduction band shifted below the Fermi level by the Li interstitial doping. As a result, 321- $\text{Li}_i$ -1 exhibited a metallic band gap. The Li impurity provides a partial 2s electron to the pristine  $\text{Ag}_2\text{S}$  system, which leads the change in band structure from a semiconducting to a metallic band gap.<sup>30</sup>

In the case of the 321- $\text{Li}_i$ -2<sub>near</sub> system with two Li interstitials, it could be confirmed that the bottom of the conduction band was reduced to a lower energy level than that of 321- $\text{Li}_i$ -1 by an additional Li 2s partial electron (Fig. 3d and f). In order to check the effect of the Li-Li interaction on the electronic structure of the Li doped- $\text{Ag}_2\text{S}$  system, the calculations for the  $3 \times 2 \times 1$   $\text{Ag}_2\text{S}$  supercells with two Li interstitials (or two Li substitutions) were performed by varying the Li-Li interdistance (See Fig. S6 or S5c-f in ESI<sup>†</sup>). However, no noticeable influence of the electronic structure on the interaction between two Li interstitials (or two Li substitutions) in the  $\text{Ag}_2\text{S}$  system was observed.

Based on the results obtained from our calculations, we proposed the following mechanism for the photoluminescence enhancement and quenching in Fig. 2e, as shown in Fig. 4. Extra carriers in Li interstitial doped  $\text{Ag}_2\text{S}$  are accumulated within the crystal, which further enhances its metallic property. By increasing the Li doping concentration, extra electrons in metallic NPs begin to migrate to original semiconducting NP outside (Step 2 in Fig. 4), thus positively charged metallic NPs can enhance the photoluminescence of the semiconducting NPs.

However, this phenomenon takes place only up to optimal doping conditions (Step 3 in Fig. 4). Above a certain doping concentration, the absolute number of semiconducting NPs

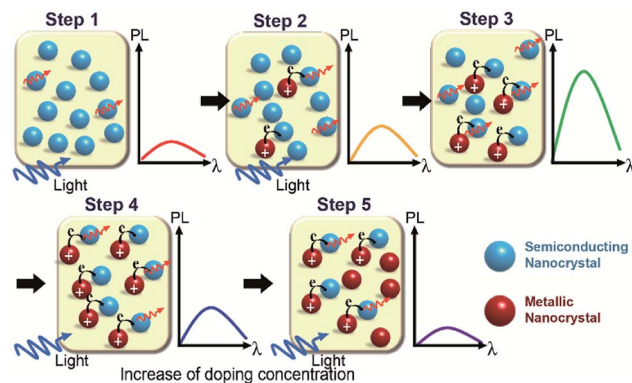
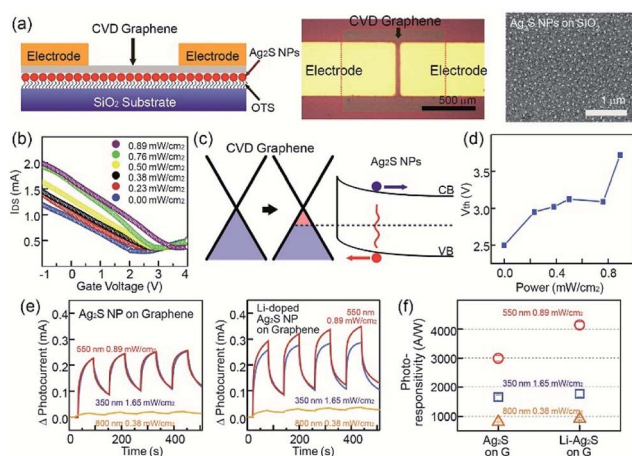


Fig. 4 Mechanism of photoluminescence enhancement and quenching Li-doped  $\text{Ag}_2\text{S}$  NPs. Schematic diagram for the mechanism of the photoluminescence enhancement and quenching in Li-doped  $\text{Ag}_2\text{S}$  NPs by increasing Li doping concentration (from Step 1 to Step 5, along the black arrow direction). The blue-sky and red balls represent the semiconducting and metallic  $\text{Ag}_2\text{S}$  NP. The blue and red wave arrows indicate the photoluminescence excitation source and light emission, respectively.

participating in the photoluminescence process are reduced compared to that of metallic NPs, and thereby the total luminescence of the sample begins to decrease rather than increase (from Step 4 to Step 5 in Fig. 4). A similar mechanism of photoluminescence enhancement and quenching has been already proposed in a previous study on Ag-doped CdSe NP.<sup>31</sup>

In addition,  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs were successfully employed for the fabrication of hybrid photodetectors based on CVD graphene and photosensitive NPs. Recently, carbon-based materials, such as carbon nanotubes, graphene oxide, and graphene have drawn considerable attention due to their superior optical, electrical, and mechanical properties.<sup>32</sup> Among carbon materials, graphene and graphene-related materials have been proposed as strong candidates for various optoelectronic applications, such as ultra-broadband photodetectors and solar cells.<sup>33</sup> However, their low optical absorption and the short recombination rate have limited their application to graphene-based optoelectronic devices. First, 1-octadecyltrichlorosilane (OTS) was utilized as self-assembled monolayer (SAM) molecules to achieve the uniform assembly of  $\text{Ag}_2\text{S}$  NPs. In this case, a UV/ozone treatment of the  $\text{SiO}_2$  surface was carried out, and the UV-treated  $\text{SiO}_2$  substrate was placed in the OTS solution to cover the  $\text{SiO}_2$  surface. When the OTS-coated  $\text{SiO}_2$  substrate was placed in the solution of methyl-terminated  $\text{Ag}_2\text{S}$  NPs, the  $\text{Ag}_2\text{S}$  NPs were assembled on the neutral-charged OTS molecular layer. CVD-grown graphene nanosheets were transferred on the top of  $\text{Ag}_2\text{S}$  NPs using a PMMA-assisted wet transfer method. Finally, Au/Cr acting as source and drain electrodes were deposited using a shadow mask, while 1-butyl-3-methylimidazolium ( $\text{BmimPF}_6$ ) was used as the ionic liquid.  $\text{Ag}_2\text{S}$  NPs were used as photosensitive materials. As shown in the image in Fig. 5a, the channel length and width of the device were 100  $\mu\text{m}$  and 500  $\mu\text{m}$ , respectively. The SEM image in Fig. 5a and atomic force microscopy (AFM) image showed that the NP density on the  $\text{SiO}_2$  substrate was uniform (See Fig. S8 in ESI<sup>†</sup>), and the NP density was





**Fig. 5** Photodetectors based on graphene and  $\text{Ag}_2\text{S}$  NPs (a) a schematic diagram of the structure of a photodetector based on graphene and  $\text{Ag}_2\text{S}$  NPs (left). Optical image of the photodetectors (middle). SEM image of graphene on  $\text{Ag}_2\text{S}$  NPs (right). (b) The transfer characteristics of a transistor based on graphene and  $\text{Ag}_2\text{S}$  NPs under various light exposing conditions. (c) A schematic energy band diagram of the Fermi level variation of graphene and  $\text{Ag}_2\text{S}$  NPs. (d) Threshold voltage of the devices as a function of light power. (e) Photocurrent of photodetector based graphene- $\text{Ag}_2\text{S}$  NPs (left) and graphene Li-doped  $\text{Ag}_2\text{S}$  NPs (right) under cyclic light exposure. Here, a light source of  $0.89 \text{ W m}^{-2}$  at 550 nm,  $1.65 \text{ W m}^{-2}$  at 350 nm, and  $0.38 \text{ W m}^{-2}$  at 800 nm was used for the measurements. (f) Photoresponsivity of photodetectors based graphene- $\text{Ag}_2\text{S}$  NPs and graphene Li-doped  $\text{Ag}_2\text{S}$  NPs obtained by light exposure of  $0.89 \text{ W m}^{-2}$  at 550 nm,  $1.65 \text{ W m}^{-2}$  at 350 nm, and  $0.38 \text{ W m}^{-2}$  at 800 nm.

approximately  $150 \mu\text{m}^{-2}$ . The transfer curve ( $I_{\text{DS}}-V_{\text{G}}$ ) of pristine graphene devices at  $V_{\text{DS}} = 0.1 \text{ V}$  exhibited a charge-neutral Dirac point at a near-zero gate voltage ( $V_{\text{G}}$ ) and an asymmetric hole and electron conduction (see Fig. S9 in ESI†). In the case of devices based on  $\text{Ag}_2\text{S}$  NPs and graphene, the Dirac voltage showed a positive shift compared with that of pristine graphene devices, and this positive shift was increased with increase of the illumination power. The electrical band structures provide a good explanation of the difference between the photodetectors based on graphene and  $\text{Ag}_2\text{S}$  NPs, as shown in Fig. 5c. The energy-band bending at the interface between a surface of graphene and  $\text{Ag}_2\text{S}$  NPs also occurred. The direction of the built-in electric field was formed from the graphene to the  $\text{Ag}_2\text{S}$  NPs. The photo-generated electrons (or holes) in the  $\text{Ag}_2\text{S}$  NPs moved within the graphene sheet with the passage of the energy band bending at the interface under the light illumination.<sup>34–36</sup> The photodetector showed an increase of current level under the exposure to a light source. Here, holes transfer from  $\text{Ag}_2\text{S}$  NPs to graphene resulted in an increase in the photocurrent (Fig. 5c). Fig. 5d shows the  $\text{Ag}_2\text{S}$ -graphene photodetector under a light exposure of 0.00, 0.23, 0.38, 0.50, 0.76, and  $0.89 \text{ mW cm}^{-2}$  exhibited a Dirac voltage of 2.2, 2.4, 2.6, 2.9, 3.0 and 3.5 V, respectively.

The photoresponse characteristics of hybrid photodetectors were evaluated by measuring the time-dependent photocurrent under various illumination conditions, such as  $0.89 \text{ W m}^{-2}$  at 550 nm,  $1.65 \text{ W m}^{-2}$  at 350 nm, and  $0.38 \text{ W m}^{-2}$  at 800 nm. First, in the case of photodevices based on pristine  $\text{Ag}_2\text{S}$  NPs,

the current through the graphene channel increased under light exposure. Moreover, we observed that the photocurrent under the light exposure at 350- and 550 nm wavelengths was larger than that under 800 nm, as shown in Fig. 5e. In addition, as previously mentioned, Li-doped  $\text{Ag}_2\text{S}$  NPs possess superior light absorption properties than pristine  $\text{Ag}_2\text{S}$  NPs, while photodetectors based on graphene and  $\text{Ag}_2\text{S}$  NPs exhibit a larger photocurrent than  $\text{Ag}_2\text{S}$  NPs. Fig. 5f shows the photoresponse of our devices under the various exposing conditions. For example, hybrid photodetectors based on  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs displayed a photoresponse of 2723.2 and  $4146.0 \text{ A W}^{-1}$ , respectively, under a light exposure of  $0.89 \text{ mW cm}^{-2}$  at 550 nm. In order to investigate the stability of the NPs, the photo and thermal stability of NPs was studied by illuminating the NPs using UV (365 nm) and heat-treated temperatures for various times. The PL emission intensities of the samples does not show much reduction in PL emission intensities, which shows the NPs have high photo and thermal stability. Moreover, to investigate the long-term air-stability, graphene photodetectors with based a graphene transistor with  $\text{Ag}_2\text{S}$  NPs and Li-doped  $\text{Ag}_2\text{S}$  NPs were placed in an environmental chamber, with a relative humidity and temperature of 50% and  $25 \text{ }^\circ\text{C}$ , respectively. Our photodetectors exhibited a similar trend with NPs data for 90 days, possibly due to charge trapping from water molecules on the graphene surface, which shows high reliability and stability of the NPs as well as photodetector devices (see Fig. S10 and S11 in ESI†).

## Experimental

### Materials

Silver nitrate ( $\text{AgNO}_3$ , 99%),  $\text{Li}_2\text{CO}_3$  (98%), and 1-dodecanethiol (DDT) were purchased from Sigma Aldrich. Chloroform and ethyl acetate were used to disperse and to isolate the NPs. All chemicals were used without further purification.

### Synthesis of $\text{Ag}_2\text{S}$ NPs and Li-doped $\text{Ag}_2\text{S}$ NPs

The  $\text{Ag}_2\text{S}$  and Li-doped  $\text{Ag}_2\text{S}$  NPs were synthesized by ultrasonication. For the synthesis of  $\text{Ag}_2\text{S}$  NPs,  $\text{AgNO}_3$  was added to a 20 mL vial containing 10 mL of DDT. The solution was treated by ultrasound irradiation for 10 min in air atmosphere. The resulting suspension was centrifuged with ethyl acetate several times to remove any by-products and dried in an electric oven at  $80 \text{ }^\circ\text{C}$ . The Li-doped  $\text{Ag}_2\text{S}$  NPs were synthesized in the same way, upon addition of the appropriate amount of lithium to the reaction bottle.

### Characterization of $\text{Ag}_2\text{S}$ and Li-doped $\text{Ag}_2\text{S}$ NPs

The absorption spectra of solutions containing 0.01 g of  $\text{Ag}_2\text{S}$  and Li-doped  $\text{Ag}_2\text{S}$  NPs (in 10 mL of chloroform) were measured using a SolidSpec-3700 UV-Vis-NIR spectrophotometer from Shimadzu. The photoluminescence (PL) spectra were measured by a Fluorolog3 with TCSPC mode (HORIBA Scientific). All samples were excited by a CW 450 W xenon source, and directed to a single-grating spectrometer. The PL spectra were obtained using a InP/InGaAs detector equipped with an LN cooler. All



TEM images were acquired on a JOEL JEM-2100F transmission electron microscope operating at 200 KV. The TEM samples were prepared by drop-casting very thin nanoparticle solutions onto a 200 mesh copper grid with a carbon film (Ted Pella). X-ray diffraction spectroscopy (XRD) for the NPs was performed using a Rigaku D/MAX-220 V X-ray diffractometer equipped with Cu K-alpha (1.540598 Å) source.

### Computational details

The atomic and electronic structures of the pristine and Li-doped Ag<sub>2</sub>S systems were examined using the Vienna *ab initio* simulation package (VASP).<sup>37,38</sup> The exchange correlation functional was approximated using the PBEsol (Perdew–Burke–Ernzerhof revised for solids) expression.<sup>39</sup> The electron–ion interactions were modeled using the projector augmented wave (PAW) method.<sup>40</sup> The electronic wave functions were expanded in a basis set of plane waves using a kinetic energy cutoff of 500 eV. Geometry relaxation steps were performed under the criterion that ionic forces were reduced below 0.02 eV Å<sup>-1</sup>. Doped Ag<sub>2</sub>S systems with interstitial and substitutional Li atoms were analyzed using a unit cell (1 × 1 × 1) and 3 × 2 × 1 supercells with 10 × 5 × 5 and 4 × 3 × 5 *k*-point meshes, respectively. The crystal data of β-Ag<sub>2</sub>S were consistent with earlier reports and were used as the lattice parameters of the pristine Ag<sub>2</sub>S system in this work.<sup>41,42</sup> The pristine Ag<sub>2</sub>S system possessed a monoclinic crystal structure (space group *P2<sub>1</sub>/c*, *a* = 4.231 Å, *b* = 6.930 Å, *c* = 9.526 Å, β = 125.48°), as shown in Fig. S7a in ESI.†

### Fabrication of photodetectors based on Ag<sub>2</sub>S (or Li-doped Ag<sub>2</sub>S NPs) and graphene

First, a SiO<sub>2</sub> surface was subjected to a UV/ozone treatment at atmospheric pressure, and then the UV-treated SiO<sub>2</sub> substrate was placed in an OTS solution (1/500 by volume ratio in anhydrous hexane). After the OTS-coated SiO<sub>2</sub> substrate was placed in a 0.16 wt% solution of Ag<sub>2</sub>S NPs and Li-doped Ag<sub>2</sub>S (total solution of 0.1 g NPs under 50 mL CHCl<sub>3</sub>) usually for about 5 minutes, the Ag<sub>2</sub>S NPs were assembled on the OTS molecular layer. CVD-grown graphene nanosheets were transferred on top of the Ag<sub>2</sub>S NPs using a PMMA-assisted wet transfer method. Au/Cr (as source/drain electrodes) were deposited using a shadow mask. In our study, Cr (7 nm)/Au (70 nm), 1-butyl-3-methylimidazolium, and Ag<sub>2</sub>S NPs were used as the source/drain electrodes, ionic liquid, and photosensitive materials, respectively.

### Conclusion

In summary, the facile preparation of Ag<sub>2</sub>S NPs and Li-doped Ag<sub>2</sub>S NPs was successfully achieved for the development of high-performance optoelectronic devices. These materials showed enhancements of absorption and emission in the NIR region through a one-step process upon ultrasonic irradiation. The effect of Li ion doping on the electronic structure of the Ag<sub>2</sub>S was also investigated by first-principles calculations, which indicated that the Li-doped Ag<sub>2</sub>S NPs could have enhanced the NIR photoluminescence and absorption abilities.

Finally, hybrid photodetectors based on transparent CVD graphene nanosheets and Ag<sub>2</sub>S NPs were successfully fabricated. These photodetectors based on pristine Ag<sub>2</sub>S NPs and Li-doped Ag<sub>2</sub>S NPs showed photoresponses of 2723.2 and 4146.0 A W<sup>-1</sup>, respectively, under a light exposure of 0.89 mW cm<sup>-2</sup> at 550 nm. This approach provides a facile high-quality synthesis method for NPs as well as a doping method for the fabrication of advanced hybrid photoelectric devices such as advanced photo-transistors, and solar cells.

### Conflicts of interest

There are no conflicts to declare.

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